## NSN 5962-01-121-1201

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View Online at https://aerobasegroup.com/nsn/5962-01-121-1201

View Offiline at https://derobasegroup.com//isi//0902-01-121-1201
Body Length:
Between 1.060 inches and 1.110 inches
Body Width:
Between 0.380 inches and 0.400 inches
Body Height:
Between 0.110 inches and 0.130 inches
Maximum Power Dissipation Rating:
1.25 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
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Features Provided:
High speed and low power and hermetically sealed
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
N-type metal oxide-semiconductor logic
Input Circuit Pattern:
19 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Time Rating Per Chacteristic:
400.00 nanoseconds propagation delay time, low to high level output
Memory Device Type:
Ram
Test Data Document:
96906-mil-std-883  standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
22 printed circuit
Shelf Life:
N/a
Unit Of Measure:
<del></del>

Demilitarization:

Yes - demil/mli

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